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•	Designed Specifically for High-Speed Memory Decoders and Data Transmission	D, N, OR PW PACKAGE (TOP VIEW)
	Systems	
•	Incorporates Two Enable Inputs to Simplify Cascading and/or Data Reception	1Y1 U 1 16 U 1Y0 1Y2 [ 2 15 ] 1A 1Y3 [ 3 14 ] 1B
•	Center-Pin V <sub>CC</sub> and GND Configurations Minimize High-Speed Switching Noise	1Y3    3 14    1B GND    4 13    1G 2Y0    5 12    V <u>C</u> C
٠	<i>EPIC</i> ™ (Enhanced-Performance Implanted CMOS) 1-μm Process	2Y1 [ 6 11 ] 2G 2Y2 [ 7 10 ] 2A
•	500-mA Typical Latch-Up Immunity at 125°C	2Y3 8 9 2B

 Package Options Include Plastic Small-Outline (D) and Thin Shrink Small-Outline (PW) Packages, and Standard Plastic 300-mil DIPs (N)

### description

The 74AC11139 circuit is designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times. In high-performance memory systems, this decoder can be used to minimize the effects of system decoding. When employed with high-speed memories utilizing a fast enable circuit, the delay times of this decoder and the enable time of the memory are usually less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

The 74AC11139 is composed of two individual 2-line to 4-line decoders in a single package. The active-low enable input can be used as a data line in demultiplexing applications. This decoder/demultiplexer features fully buffered inputs, each of which represents only one normalized load to its driving circuit.

The 74AC11139 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE									
ENABLE INPUT	-	ECT UTS	OUTPUTS						
G	Α	В	Y0	Y1	Y2	Y3			
н	Х	Х	Н	Н	Н	Н			
L	L	L	L	Н	Н	н			
L	н	L	н	L	н	н			
L	L	н	н	Н	L	н			
L	н	Н	н	Н	Н	L			

FUNCTION TABLE



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

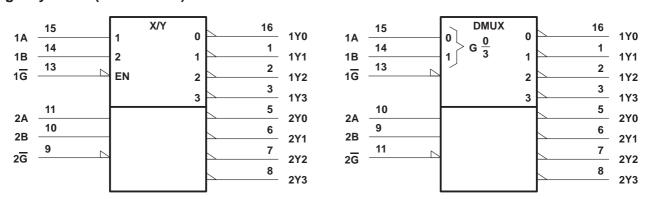
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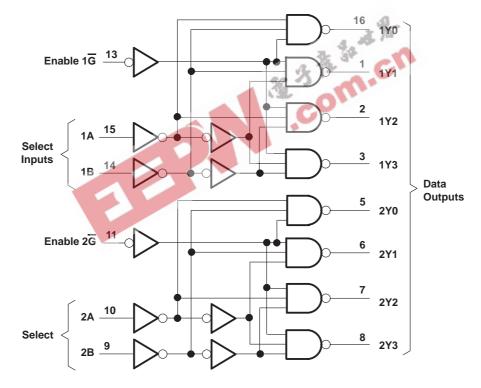
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## logic symbols (alternatives)<sup>†</sup>



<sup>†</sup> These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## logic diagram (positive logic)





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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, $V_{CC}$ Input voltage range, $V_I$ (see Note 1) Output voltage range, $V_O$ (see Note 1) Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ ) Output clamp current, $I_{OK}$ ( $V_O < 0$ or $V_O > V_{CC}$ ) Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ ) Continuous current through $V_{CC}$ or GND Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 2)	-0.5 V to V <sub>CC</sub> + 0.5 V -0.5 V to V <sub>CC</sub> + 0.5 V ±20 mA ±50 mA ±50 mA ±200 mA ±200 mA 1.3 W N package
Storage temperature range, T <sub>stg</sub>	PW package 0.5 W 65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
  - 2. The maximum package power dissipation is calculated using a junction temperature of 150 °C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

	except for the N package, which has a trace length of zero.	a state			
ecom	mended operating conditions	1 12 CA	MIN	NOM MAX	UNIT
V <sub>CC</sub>	Supply voltage	3	3	5 5.5	V
		V <sub>CC</sub> = 3 V	2.1		
VIH	High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15		V
		V <sub>CC</sub> = 5.5 V	3.85		1
VIL		V <sub>CC</sub> = 3 V		0.9	
	Low-level input voltage	V <sub>CC</sub> = 4.5 V		1.35	V
		V <sub>CC</sub> = 5.5 V		1.65	]
VI	Input voltage		0	VCC	V
Vo	Output voltage		0	VCC	V
		V <sub>CC</sub> = 3 V		-4	
ЮН	High-level output current	$V_{CC} = 4.5 V$		-24	mA
		V <sub>CC</sub> = 5.5 V		-24	1
		V <sub>CC</sub> = 3 V		12	
IOL	Low-level output current	V <sub>CC</sub> = 4.5 V		24	mA
		V <sub>CC</sub> = 5.5 V		24	1
Δt/Δv	Input transition rise or fall rate		0	10	ns/V
TA	Operating free-air temperature		-40	85	°C

### recommended operating conditions



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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vcc	T <sub>A</sub> = 25°C		MIN	МАХ	UNIT
FARAINETER	TEST CONDITIONS		MIN TYP	MAX	IVIIIN		UNIT
			2.9		2.9		
	I <sub>OH</sub> = -50 μA	4.5 V	4.4		4.4		
		5.5 V	5.4	5.4			
VOH	$I_{OH} = -4 \text{ mA}$	3 V	2.58		2.48		V
		4.5 V	3.94		3.8		
	I <sub>OH</sub> = -24 mA	5.5 V	4.94	4.8			
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V			3.85		
		3 V		0.1		0.1	
	I <sub>OL</sub> = 50 μA	4.5 V		0.1		0.1	
				0.1		0.1	
V <sub>OL</sub>	I <sub>OL</sub> = 12 mA	3 V		0.36		0.44	V
	la = 24  m	4.5 V	0	0.36		0.44	
	I <sub>OL</sub> = 24 mA	5.5 V	3 6	0.36		0.44	
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V	10			1.65	
lı	$V_{I} = V_{CC}$ or GND	5.5 V		±0.1		±1	μA
ICC	$V_{I} = V_{CC} \text{ or GND},$ $I_{O} = 0$	5.5 V		8		80	μA
Ci	VI = V <sub>CC</sub> or GND	5 V	3.5				pF

<sup>†</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T <sub>A</sub> = 25°C			MIN	мах	UNIT
PARAMETER			MIN	TYP	MAX		IVIAA	
<sup>t</sup> PLH	A or B	Y	1.5	5.3	8.1	1.5	9	ns
<sup>t</sup> PHL			1.5	6	8.4	1.5	9.4	
<sup>t</sup> PLH	-	×	1.5	5.3	6.9	1.5	7.6	20
<sup>t</sup> PHL	G	I	1.5	5.6	7.4	1.5	8.1	ns

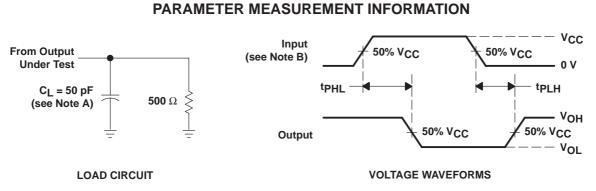
# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T <sub>A</sub> = 25°C			MIN	мах	UNIT
PARAMETER			MIN	TYP	MAX		IVIAA	UNIT
<sup>t</sup> PLH	A or B	Y	1.5	3.5	6	1.5	6.6	ns
<sup>t</sup> PHL			1.5	4.1	6.3	1.5	6.9	
<sup>t</sup> PLH	-	V	1.5	3.8	5.2	1.5	5.7	-
<sup>t</sup> PHL	G	ſ	1.5	4	5.6	1.5	6.2	ns

## operating characteristics, V\_{CC} = 5 V, T<sub>A</sub> = 25°C

PARAMETER		TEST COM	TYP	UNIT	
C <sub>pd</sub>	Power dissipation capacitance per gate	C <sub>L</sub> = 50 pF,	f = 1 MHz	47	pF

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NOTES: A. CL includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub> = 3 ns, t<sub>f</sub> = 3 ns.
- C. The outputs are measured one at a time with one input transition per measurement.

#### Figure 1. Load Circuit and Voltage Waveforms





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